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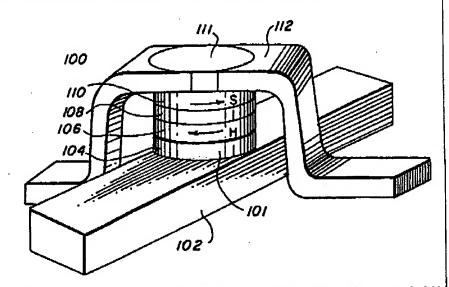
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(54) Title: ULTRA HIGH DENSITY, NON-VOLATILE FERROMAGNETIC RANDOM ACCESS MEMORY

(57) Abstract

mobus **2000S**8 memory element (100) utilizes giant magnetoresistance. The element (100) includes at least one pair of ferromagnetic layers (106, 110) sandwiching a popmagnetic conductive layer (108). At least one of the two ferromagnetic layers has a magnetic moment oriented within its own plane. The magnetic moment of at least the first ferromagnetic, layer of the pair has its magnetic moment oriented within its own plane and is typically fixed in direction during use. The second ferromagnetic layer of the pair has a magnetic moment which has at least two preferred directions of orientation which may or may not reside within



the plane of the second ferromagnetic layer. The bit of the memory element may be set by applying to the element a magnetic field which orients the magnetic moment of the second ferromagnetic layer in one or the other of these preferred orientations. The set value is determined by the relative alignment of the magnetic moments of the first and second ferromagnetic layers.

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